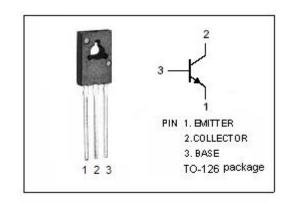


isc Silicon NPN Power Transistor

2SC1212A

DESCRIPTION

- High Collector Current -I_C= 1A
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 80V(Min)
- · Good Linearity of hFE
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

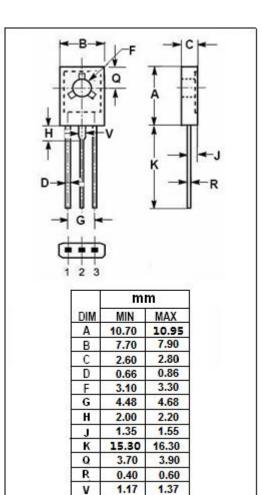


APPLICATIONS

• Designed for low frequency power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage 80 \		V	
V _{CEO}	Collector-Emitter Voltage 80 V		V	
V _{EBO}	Emitter-Base Voltage 4 V		V	
Ic	Collector Current-Continuous	1	Α	
Pc	Collector Power Dissipation @ T _C =25℃	8	W	
	Collector Power Dissipation @ T _a =25℃	0.75		
TJ	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	





isc Silicon NPN Power Transistor

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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA ; I _E = 0	80			V
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA ; R _{BE} = ∞	80			V
V _{(BR)EBO}	Emitter-Base Breakdown Vltage	I _E = 1mA ; I _C = 0	4			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 1A; I _B = 0.1A			1.5	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 50mA ; V _{CE} = 4V			1.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 50V; I _E = 0			5	μА
h _{FE-1}	DC Current Gain	Ic= 50mA; Vc== 4V	60		200	
h _{FE-2}	DC Current Gain	I _C = 1A; V _{CE} = 4V	20			
f⊤	Current-Gain—Bandwidth Product	I _C = 30mA ; V _{CE} = 4V		160		MHz

♦ h_{FE-1} Classifications

В	С		
60-120	100-200		

NOTICE:

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